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3.3W Mono Class DG Multilevel Audio Amplifier

General Description

The MAX98307/MAX98308 fully differential mono Class DG multilevel power amplifiers with integrated inverting charge pumps offer highly efficient, high-power audio solutions for portable applications.

Class DG multilevel modulation extends the dynamic range of the output signal by employing a charge-pumpgenerated negative rail as needed to extend the supply range. This scheme results in high efficiency over a wide output power range.

The ICs combine Maxim's active emissions limiting edge rate and overshoot control circuitry with multilevel output modulation to greatly reduce EMI. These features eliminate the need for output filtering as compared to traditional Class D devices, reducing component count and cost.

The MAX98307's 16-pin TQFN package features an adjustable gain set by external resistors. The MAX98308's space-saving 12-bump WLP package features an internally fixed gain of 8.5dB, 11.5dB, 14.5dB, 17.5dB, and 20.5dB set by a single gain input. Both devices operate over the extended -40°C to +85°C temperature range.

Applications

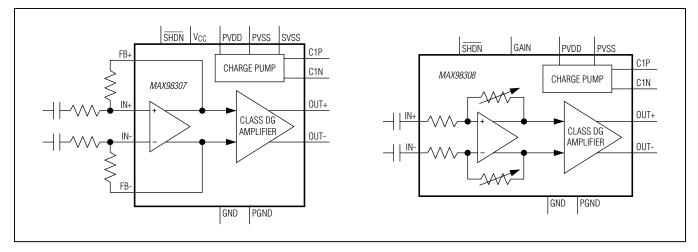
Cellular PhonesVoIP PlSmartphonesPortablNotebook ComputersTablet

VoIP Phones Portable Audio Tablet PCs

Benefits and Features

- ♦ High Efficiency Combined with High Output Power
 ♦ Class DG Multilevel Modulation Ensures Maximum Efficiency Over Wide Output Power Range
- ◆ High Output Power at 1% THD+N
 - \diamond 1.54W at V_{PVDD} = 3.6V, 8Ω + 68µH Load \diamond 2.85W at V_{PVDD} = 5V, 8Ω + 68µH Load
- ♦ High Output Power at 10% THD+N
 ♦ 1.77W at V_{PVDD} = 3.6V, 8Ω + 68µH Load
 ♦ 3.3W at V_{PVDD} = 5V, 8Ω + 68µH Load
- ♦ 84% Efficiency (V_{PVDD} = 3.6V, at 500mW Output)
- Active Emissions Limiting and Class DG Multilevel Output Modulation Eliminates EMI Output Filtering Requirement
- Integrated Charge Pump and High Efficiency Results in Small Solution Size
- Excellent RF Immunity
- Click-and-Pop Suppression
- Thermal and Overcurrent Protection
- Low-Current Shutdown Mode

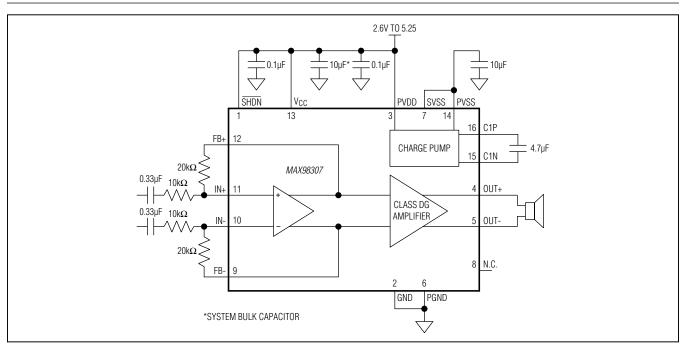
Ordering Information appears at end of data sheet.



For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maximintegrated.com.

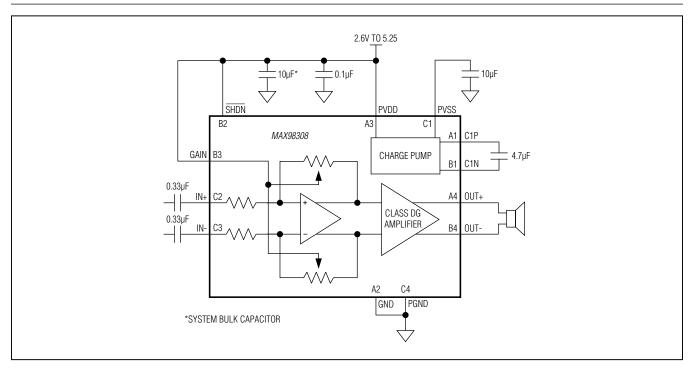
Simplified Block Diagrams

3.3W Mono Class DG Multilevel Audio Amplifier



MAX98307 Typical Application Circuit

MAX98308 Typical Application Circuit



3.3W Mono Class DG Multilevel Audio Amplifier

ABSOLUTE MAXIMUM RATINGS

PVDD to GND	0.3V to +6V
PGND to GND	0.3V to +0.3V
C1N to GND	. (V _{PVSS} - 0.3V) to +0.3V
IN+, IN- (MAX98307)	0.3V to (V_{CC} + 0.3V)
V _{CC} to PVDD (MAX98307)	0.3V to +0.3V
PVSS to SVSS (MAX97307)	0.3V to +0.3V
PVSS, SVSS to GND (MAX98307)	6V to +0.3V
IN+, IN- (MAX98308)	0.3V to +6V
PVSS to GND (MAX98308)	6V to +0.3V
All Other Pins to GND	0.3V to (V _{PVDD} + 0.3V)
Continuous Current Into/Out of PVDD,	V _{CC} , PGND, GND,
OUT+, OUT-, C1P, C1N, PVSS, SVS	S ±800mA

Continuous Current (all other pins)±20mA Duration of OUT+/OUT- Short Circuit to PGND	
or PVDD	
Short-Circuit Duration Between	
OUT+ and OUT- PinsContinuous	
Continuous Power Dissipation ($T_A = +70^{\circ}C$) for Multilayer Board	
TQFN (derate 20.8mW/°C above +70°C)1667mW	
WLP (derate 13.7mW/°C above +70°C)1100mW	
Junction Temperature+150°C	
Operating Temperature Range40°C to +85°C	
Storage Temperature Range65°C to +150°C	
Lead Temperature (soldering, 10s) (TQFN-EP) +300°C	
Soldering Temperature (reflow)+260°C	
nent damage to the device. These are stress ratings only, and functional opera-	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

PACKAGE THERMAL CHARACTERISTICS (Note 1)

IQFIN

 WLP

- Junction-to-Ambient Thermal Resistance (θ_{JA}).......73°C/W Junction-to-Case Thermal Resistance (θ_{JC})............30°C/W
- Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <u>www.maximintegrated.com/thermal-tutorial</u>.

ELECTRICAL CHARACTERISTICS

 $\begin{array}{l} V_{PVDD} = V_{CC} = V_{\overline{SHDN}} = 3.6V, \ V_{PGND} = V_{GND} = 0V, \ Z_L = 8\Omega + 68\mu \text{H} \ \text{between OUT+ and OUT-, (MAX98307 R_{IN+} = R_{IN-} = 10k\Omega, R_{FB+} = R_{FB-} = 20k\Omega), \ C_{IN+} = C_{IN-} = 0.33\mu \text{F}, \ A_V = 14.5 \text{dB}, \ \text{AC} \ \text{measurement bandwidth 20Hz to 20kHz}, \ T_A = T_{MIN} \ \text{to } T_{MAX}, \ \text{unless otherwise noted.} \ \text{Typical values are at } T_A = +25^{\circ}\text{C.} \ \text{(Notes 2, 3)} \end{array}$

PARAMETER	SYMBOL	CON	DITIONS	MIN	ТҮР	MAX	UNITS
Power-Supply Range	VPVDD, VCC	Guaranteed by PSF	R test	2.6		5.25	V
Quiescent Current	IDD	VPVDD = 3.6V			1.85	2.7	mA
Shutdown Current	ISHDN	SHDN = GND			0.225	10	μA
		VPVDD = 2.6V to 5.2	25V		78		
Power-Supply Rejection Ratio	PSRR	f = 217Hz, 200mVP	-P ripple		78		dB
(Note 4)		f = 10kHz, 200mVP-	f = 10kHz, 200mVP-P ripple		67		
		Time from shutdown or	MAX98308		25	40	ms
Turn-On Time	tON	power-on to full operation	MAX98307, RIN = 10kΩ		50	80	
Input DC Bias Voltage	VBIAS				1.3		V
	Rin	AV = 20.5dB (maxir	num gain)	15	22		
Input Resistance (MAX98308)		AV = 17.5dB			22		
		AV = 14.5dB			22		kΩ
		AV = 11.5dB			28		-
		AV = 8.5dB			40		

3.3W Mono Class DG Multilevel Audio Amplifier

ELECTRICAL CHARACTERISTICS (continued)

 $V_{PVDD} = V_{CC} = V_{\overline{SHDN}} = 3.6V, V_{PGND} = V_{GND} = 0V, Z_L = 8\Omega + 68\mu\text{H between OUT+ and OUT-, (MAX98307 R_{IN+} = R_{IN-} = 10k\Omega, R_{FB+} = R_{FB-} = 20k\Omega), C_{IN+} = C_{IN-} = 0.33\mu\text{F}, A_V = 14.5dB, AC measurement bandwidth 20Hz to 20kHz, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)$

PARAMETER	SYMBOL	СО	NDITIONS	MIN	ТҮР	MAX	UNITS
		GAIN = short to GND		20	20.5	21	
Voltage Gain (MAX98308)		GAIN = $100k\Omega$ pulldown to GND		17	17.5	18	dB
	AV	GAIN = short to PVDD		14	14.5	15	
(MAX30300)		GAIN = $100k\Omega$ pullup to PVDD		11	11.5	12	
		GAIN = unconnec	ted	8	8.5	9	
Common-Mode Rejection Ratio (MAX98308)	CMRR	fIN = 1kHz			65		dB
			$ZL = 8\Omega + 68\mu H,$ $VPVDD = 3.6V$		1.54		
		fIN = 1kHz, THD+N = 1%	$ZL = 8\Omega + 68\mu H,$ $VPVDD = 4.2V$		2		- W
O. to the Dourse (MAN/00007)	Pout		$ZL = 8\Omega + 68\mu H,$ $VPVDD = 5.0V$		2.85		
Output Power (MAX98307)		fiN = 1kHz, THD+N = 10%	$ZL = 8\Omega + 68\mu H,$ $VPVDD = 3.6V$		1.77		
			$ZL = 8\Omega + 68\mu H,$ $VPVDD = 4.2V$		2.3		
			$ZL = 8\Omega + 68\mu H,$ VPVDD = 5.0V		3.3		
		THD+N ≤ 1%	ZSPK = $8\Omega + 68\mu$ H, VPVDD = 3.6V		1.4		- - W
Output Power (MAX98308)	Pout		$ZSPK = 8\Omega + 68\mu H,$ $VPVDD = 4.2V$		1.92		
			ZSPK = $8\Omega + 68\mu$ H, VPVDD = 5.0V		2.7		
		THD+N ≤ 10%	ZSPK = $8\Omega + 68\mu$ H, VPVDD = 3.6V		1.57		
			$ZSPK = 8\Omega + 68\mu H,$ VPVDD = 4.2V		2.13		1

3.3W Mono Class DG Multilevel Audio Amplifier

ELECTRICAL CHARACTERISTICS (continued)

 $\begin{array}{l} V_{PVDD} = V_{CC} = V_{\overline{SHDN}} = 3.6V, \ V_{PGND} = V_{GND} = 0V, \ Z_L = 8\Omega + 68\mu\text{H} \ \text{between OUT+ and OUT-, (MAX98307 R_{IN+} = R_{IN-} = 10k\Omega, R_{FB+} = R_{FB-} = 20k\Omega), \ C_{IN+} = C_{IN-} = 0.33\mu\text{F}, \ A_V = 14.5dB, \ \text{AC} \ \text{measurement bandwidth 20Hz to 20kHz}, \ T_A = T_{MIN} \ \text{to } T_{MAX}, \ \text{unless otherwise noted.} \ \text{Typical values are at } T_A = +25^\circ\text{C.} \ \text{(Notes 2, 3)} \end{array}$

PARAMETER	SYMBOL	CONDITI	ONS	MIN	ТҮР	МАХ	UNITS
Total Harmonic Distortion Plus Noise	THD+N	fIN = 1kHz, POUT = 1W			0.05		%
Output Offset Voltage	Vos	TA = +25°C			±1	±5	mV
Oligic and Dan Laval	Kop	Peak voltage, A-weighted,			-65		
Click-and-Pop Level	КСР	32 samples per second (Notes 4, 5) Out of shutdown		-65		dBV	
Output Switching Frequency					340		kHz
Efficiency	η	fIN = 1kHz, POUT at 500mW, THD+N = 0.02%			84		%
		fIN = 1kHz, POUT at 1W	′, THD+N = 0.05%		82		
Current Limit	ILIM				2		ARMS
Output Noise	VN	A-weighted			52		μVRMS
LOGIC INPUT (SHDN)							
Input Voltage High	VIH			1.4			V
Input Voltage Low	VIL					0.4	V
Input Leakage Current		TA = +25°C				±10	μA

Note 2: 100% production tested at $T_A = +25^{\circ}C$. Specifications over temperature limits are guaranteed by design.

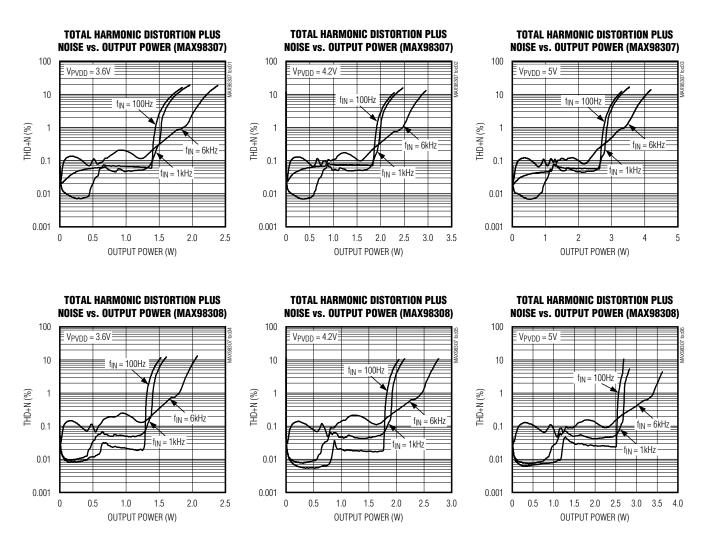
Note 3: Testing performed with a resistive load in series with an inductor to simulate an actual speaker. For $R_L = 8\Omega$, $L = 68\mu$ H. **Note 4:** Amplifier inputs AC-coupled to GND.

Note 5: Specified at room temperature with an 8Ω resistive load in series with a 68µH inductive load connected across the BTL outputs. Mode transitions controlled by SHDN active-low shutdown control.

3.3W Mono Class DG Multilevel Audio Amplifier

Typical Operating Characteristics

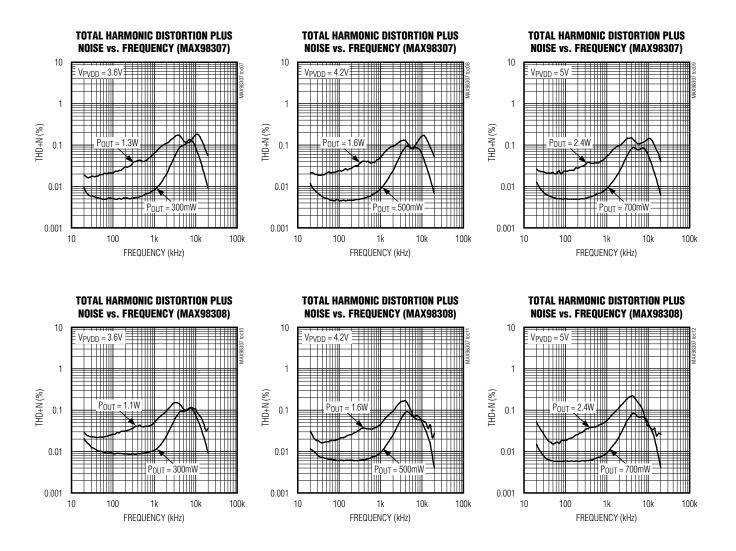
 $(V_{PVDD} = V_{CC} = V_{\overline{SHDN}} = 3.6V, V_{PGND} = V_{GND} = 0V, Z_L = 8\Omega + 68\mu H \text{ between OUT+ and OUT-, } A_V = 14.5dB \text{ (MAX98307 } R_{IN+} = R_{IN-} = 10k\Omega, R_{FB+} = R_{FB-} = 20k\Omega), C_{IN+} = C_{IN-} = 0.33\mu F, AC \text{ measurement bandwidth 20Hz to 20kHz.}$



3.3W Mono Class DG Multilevel Audio Amplifier

Typical Operating Characteristics (continued)

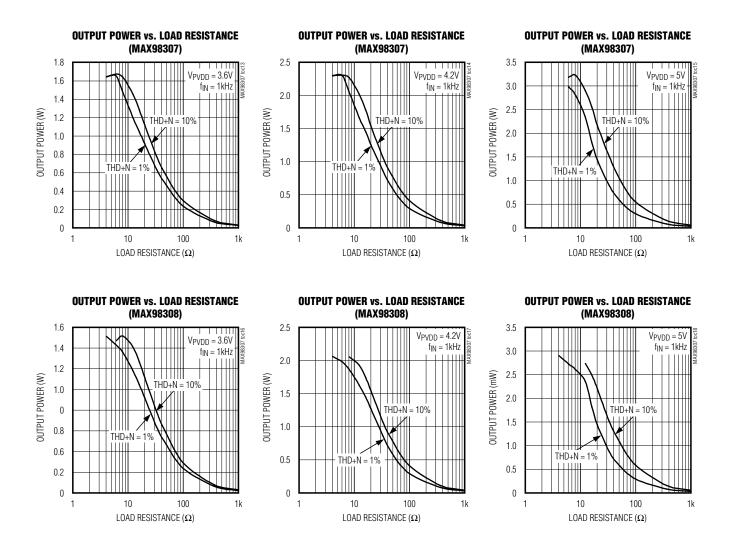
 $(V_{PVDD} = V_{CC} = V_{\overline{SHDN}} = 3.6V, V_{PGND} = V_{GND} = 0V, Z_L = 8\Omega + 68\mu\text{H between OUT+ and OUT-, } A_V = 14.5dB \text{ (MAX98307 } \text{R}_{\text{IN+}} = \text{R}_{\text{IN-}} = 10k\Omega, \text{R}_{\text{FB+}} = \text{R}_{\text{FB-}} = 20k\Omega), C_{\text{IN+}} = C_{\text{IN-}} = 0.33\mu\text{F}, \text{ AC measurement bandwidth 20Hz to 20kHz.}$



3.3W Mono Class DG Multilevel Audio Amplifier

Typical Operating Characteristics (continued)

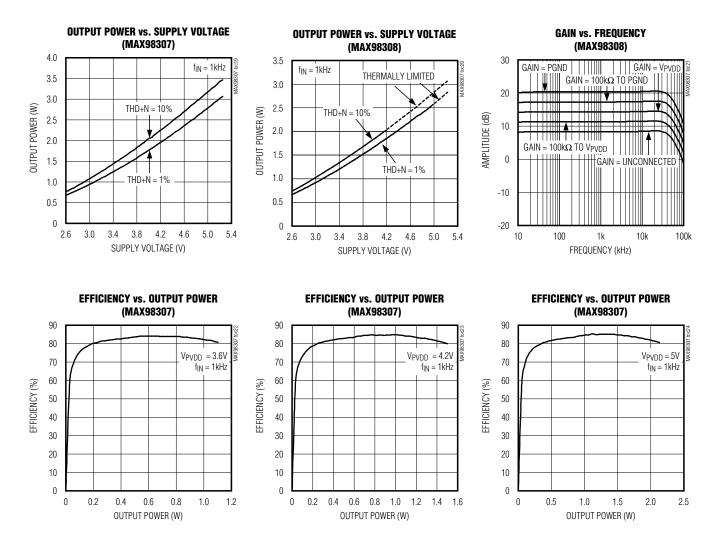
 $(V_{PVDD} = V_{CC} = V_{\overline{SHDN}} = 3.6V, V_{PGND} = V_{GND} = 0V, Z_L = 8\Omega + 68\mu\text{H between OUT+ and OUT-, } A_V = 14.5dB \text{ (MAX98307 } \text{R}_{\text{IN+}} = \text{R}_{\text{IN-}} = 10k\Omega, \text{R}_{\text{FB+}} = \text{R}_{\text{FB-}} = 20k\Omega), C_{\text{IN+}} = C_{\text{IN-}} = 0.33\mu\text{F}, \text{ AC measurement bandwidth 20Hz to 20kHz.}$



3.3W Mono Class DG Multilevel Audio Amplifier

Typical Operating Characteristics (continued)

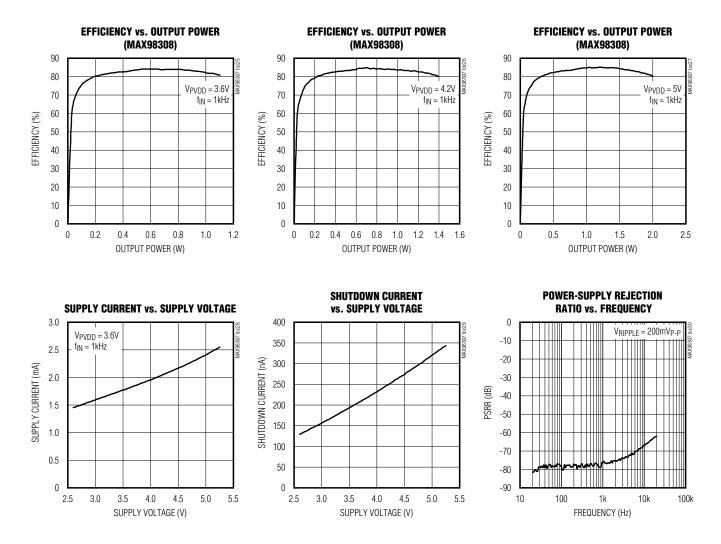
 $(V_{PVDD} = V_{CC} = V_{\overline{SHDN}} = 3.6V, V_{PGND} = V_{GND} = 0V, Z_L = 8\Omega + 68\mu$ H between OUT+ and OUT-, A_V = 14.5dB (MAX98307 R_{IN+} = R_{IN-} = 10k Ω , R_{FB+} = R_{FB-} = 20k Ω), C_{IN+} = C_{IN-} = 0.33 μ F, AC measurement bandwidth 20Hz to 20kHz.)



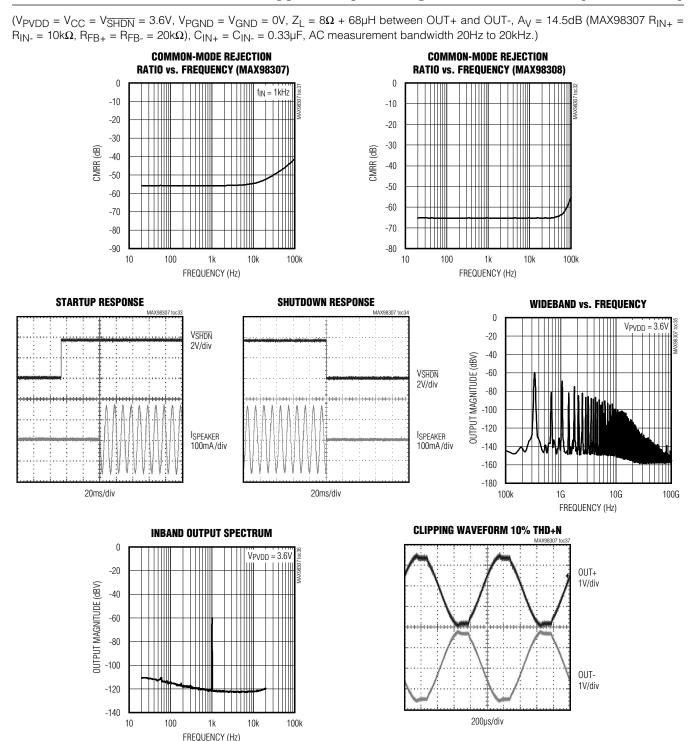
3.3W Mono Class DG Multilevel Audio Amplifier

$\label{eq:transformation} \hline \textbf{Typical Operating Characteristics (continued)} \\ (V_{PVDD} = V_{CC} = V_{\overline{SHDN}} = 3.6V, V_{PGND} = V_{GND} = 0V, Z_L = 8\Omega + 68\mu\text{H between OUT+ and OUT-, } A_V = 14.5\text{dB} (MAX98307 \ \text{R}_{\text{IN+}} = 14.5\text{dB} (MAX98307 \ \text{R}$

 $(V_{PVDD} = V_{CC} = V_{\overline{SHDN}} = 3.6V, V_{PGND} = V_{GND} = 0V, Z_L = 8\Omega + 68\mu$ H between OUT+ and OUT-, A_V = 14.5dB (MAX98307 R_{IN+} = R_{IN-} = 10k Ω , R_{FB+} = R_{FB-} = 20k Ω), C_{IN+} = C_{IN-} = 0.33 μ F, AC measurement bandwidth 20Hz to 20kHz.)



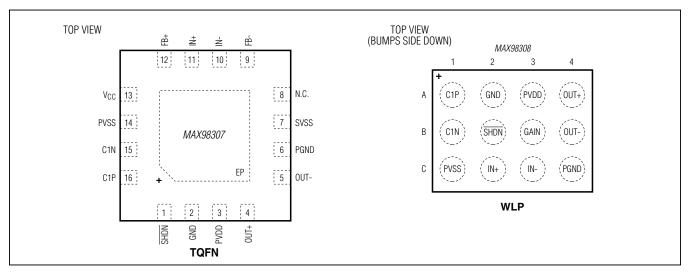
3.3W Mono Class DG Multilevel Audio Amplifier



Typical Operating Characteristics (continued)

Maxim Integrated

3.3W Mono Class DG Multilevel Audio Amplifier



Pin/Bump Configurations

Pin/Bump Description

PIN	BUMP			
MAX98307	MAX98308	NAME	FUNCTION	
1	B2	SHDN	Active-Low Shutdown. Connect to GND for shutdown. Connect to PVDD for normal operation.	
2	A2	GND	Substrate and Signal Ground	
3	A3	PVDD	Power and Charge-Pump Supply. Bypass to PGND with a 0.1µF capacitor.	
4	A4	OUT+	Positive Amplifier Output	
5	B4	OUT-	Negative Amplifier Output	
6	C4	PGND	Power Ground	
7		SVSS	Amplifier Negative Power Supply. Connect to PVSS (MAX98307).	
8		N.C.	No Connection. Not internally connected. Connect to GND or leave unconnected.	
9		FB-	Negative Amplifier Feedback	
10	C3	IN-	Negative Amplifier Input	
11	C2	IN+	Positive Amplifier Input	
12	_	FB+	Positive Amplifier Feedback	
	B3	GAIN	See Table 1 MAX98308 Gain Configuration for more information.	
13	_	V _{CC}	Signal Supply	
14	C1	PVSS	Charge-Pump Output. Connect a 10µF capacitor between PVSS and PGND.	
15	B1	C1N	Charge-Pump Flying Capacitor Negative Terminal. Connect a 4.7µF capacitor between C1N and C1P.	
16	A1	C1P	Charge-Pump Flying Capacitor Positive Terminal. Connect a 4.7µF capacitor between C1N and C1P.	
_		EP	Exposed Pad (TQFN Only). Internally connected to GND. Connect to a large ground plane with multiple vias to maximize thermal performance. Not intended as an electrical connection point.	

3.3W Mono Class DG Multilevel Audio Amplifier

Detailed Description

The MAX98307/MAX98308 fully differential mono Class DG multilevel power amplifiers with integrated inverting charge pumps offer highly efficient, high-power audio solutions for portable applications.

The new Class DG multilevel modulation scheme extends the dynamic range of the output signal by employing a charge-pump-generated negative rail, which is used as needed to extend the supply range. When the negative rail is not needed, the output is drawn entirely from the standard supply. This scheme results in high efficiency over a wide output power range.

The power amplifier incorporates active emissions limiting edge rate and overshoot control circuitry in combination with the multilevel output modulation scheme to greatly reduce EMI. These features eliminate the need for output filtering as compared to traditional Class D amplifiers, which reduces an application's component count.

The MAX98307 has an adjustable gain set by external resistors. The MAX98308 has preset fixed gains of 8.5dB, 11.5dB, 14.5dB, 17.5dB, and 20.5dB set by a gain select input (GAIN).

Class DG Multilevel Operation

The ICs' filterless Class DG multilevel amplifiers feature a proprietary Maxim output stage that offers higher efficiency over a greater output power range than previous amplifiers. The amplifier combines Class D switching output efficiency and Class G supply level shifting with a multilevel output modulation scheme that with a 5V supply has efficiency better than 80% efficiency over the 0.35W to 2.2W output range.

The Class DG multilevel output stage uses pulse-width modulation (PWM), a rail-to-rail digital output signal with variable duty cycle, to approximate an analog input signal as in a Class D amplifier. Rail-to-rail operation ensures that any dissipation at the output is due solely to the R_{DS(ON)} of the power output MOSFETs. The Class DG multilevel output stage also senses the magnitude of the output signal and switches the supply rails as needed to more

efficiently supply the required signal power. For a low output signal swing requirement (below the battery supply rail V_{PVDD}), the output range is between V_{PVDD} and ground. When output swing above V_{PVDD} is required, V_{PVSS}, an internal inverting charge-pump-generated negative rail replaces ground as the lower supply. The high output swing range is then V_{PVDD} to V_{PVSS}, approximately double the low swing range. This approach efficiently manages power consumption by switching the operating rails as needed according to the output swing requirements. Additionally, multilevel output modulation is employed in to draw the maximum possible power from the lower impedance battery supply rail, V_{PVDD}, rather than the higher impedance charge-pump-generated rail VPVSS. This is accomplished by generating PWM signals that swing from ground to V_{PVDD} or from ground to V_{PVSS} at either end of the bridge tied load (BTL) rather than continually swinging from V_{PVDD} to V_{PVSS}. The signals are modulated in such a way that V_{PVSS} is used only as necessary to generate low-end signal swing.

These combined operations ensure that power dissipation due to $R_{DS(ON)}$ loss and charge-pump impedance is minimized, and that efficiency and output power is maximized across the audio range. Class DG multilevel operation is shown as Figure 1.

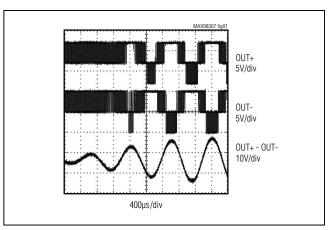


Figure 1. Class DG Multilevel Operation

3.3W Mono Class DG Multilevel Audio Amplifier

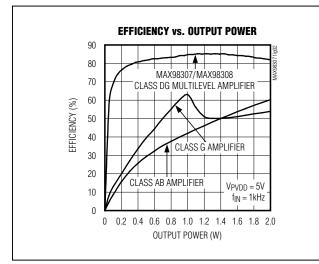


Figure 2. Class DG Multilevel vs. Typical Class G and Class AB Amplifier Efficiency

The Class DG multilevel efficiency compares favorably with Class AB and Class G amplifiers as shown in Figure 2. Note that efficiency at 1W is 85%.

EMI Filterless Output Stage

Traditional Class D amplifiers require the use of external LC filters, or shielding, to meet electromagnetic-interference (EMI) regulation standards. The active emissions limiting edge-rate control circuitry and Class DG multilevel modulation scheme reduce EMI emissions without the need for external filtering components, while maintaining high efficiency (see Figure 3).

Amplifier Current Limit

If the output current of the speaker amplifier exceeds the current limit, the ICs disable the outputs for approximately 100 μ s. After 100 μ s, the outputs are reenabled. If the fault condition still exists, the ICs continue to disable and reenable the outputs until the fault condition is removed.

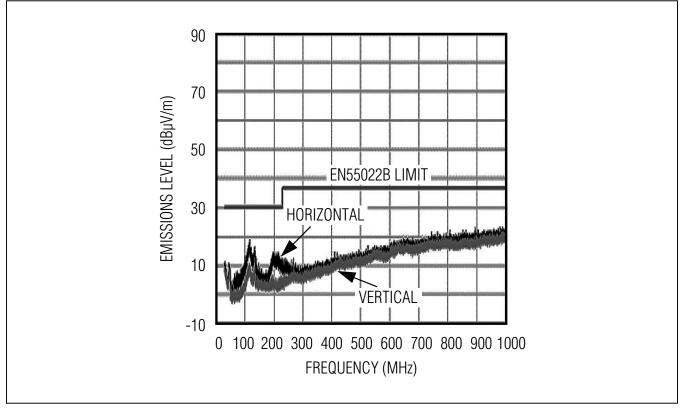


Figure 3. EMI Performance with V_{PVDD} = 5V, 12in of Speaker Cable, No Output Filter

3.3W Mono Class DG Multilevel Audio Amplifier

Click-and-Pop Suppression

The speaker amplifier features Maxim's comprehensive click-and-pop suppression. During startup, the click-and-pop suppression circuitry reduces any audible transient sources internal to the device. When entering shutdown, the differential speaker outputs quickly and simultaneously ramp down to PGND.

Thermal and Short Circuit Protection

The ICs automatically enter thermal shutdown when the die temperature is greater than +160°C and reactivate at less than +135°C. Additionally, if the outputs are shorted to each other or either rail, the amplifier prevents catastrophic loss by disabling the outputs.

Shutdown

The ICs feature a low-power shutdown mode, drawing less than $0.225\mu A$ (typ) supply current. Drive \overline{SHDN} low to put the IC into the shutdown state.

Applications Information

Filterless Class DG Operation

Traditional Class DG amplifiers require an output filter. The filter adds cost and size, as well as decreases efficiency and THD+N performance. The ICs' active emissions limiting and Class DG multilevel output modulation allow for filterless operation while reducing external component count, and thereby, cost.

Because the switching frequency of the ICs is well beyond the bandwidth of most speakers, voice coil movement due to the switching frequency is very small. Use a speaker with a series inductance > 10 μ H. Typical 8 Ω speakers exhibit series inductances in the 20 μ H to 100 μ H range.

Differential Input Amplifier

The ICs feature a differential input configuration, making the device compatible with many codecs and offering improved noise immunity as compared to single-ended input amplifiers. In devices such as mobile phones, noisy digital signals can be picked up by an amplifier's input traces. A differential amplifier amplifies the difference of the two inputs, while signals common to both inputs, such as switching noise, are rejected. While both ICs feature differential amplifiers, their voltage gain is set in differing manners.

The MAX98307 employs external feedback resistors as shown in Figure 4. Voltage gain of the input amplifier is set as:

$$A_V = 20 \log \left(\frac{R_{FB}}{R_{IN}} \right) (dB) + 8.5 dB$$

A

where A_V is the desired voltage gain in decibels. R_{IN+} should be equal to R_{IN-} , and R_{FB+} should be equal to R_{FB-} .

In differential input configurations, the common-mode rejection ratio (CMRR) is primarily limited by the external resistor and capacitor matching. Ideally, to achieve the highest possible CMRR, the following external components should be selected where:

$$\frac{R_{FB+}}{R_{IN+}} = \frac{R_{FB-}}{R_{IN-}}$$

and
$$C_{IN+} = C_{IN-}$$

The gain of the MAX98308 is selectable by connecting the gain-select bump GAIN as described in Table 1.

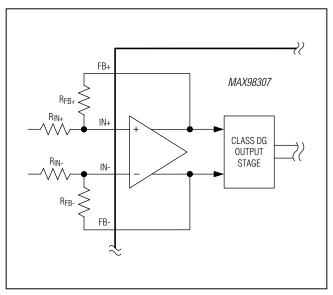


Figure 4. Setting the Voltage Gain of the MAX98307

3.3W Mono Class DG Multilevel Audio Amplifier

GAIN	PREAMPLIFIER GAIN (dB)	OVERALL GAIN (dB)
Unconnected	0	8.5
100k Ω to V _{PVDD}	3	11.5
Short to V _{PVDD}	6	14.5
100k Ω to PGND	9	17.5
Short to PGND	12	20.5

Table 1. MAX98308 Gain Configuration

Note: For both ICs, the Class DG output stage has a fixed gain of 8.5dB. Any gain or attenuation set by the external input stage resistors adds to or subtracts from this fixed gain.

Component Selection Power-Supply Input (PVDD)

PVDD powers the speaker amplifier and has a range of 2.6V to 5.25V. Bypass PVDD with 0.1μ F and 10μ F capacitors in parallel to PGND. Apply additional bulk capacitance at the device if long input traces between PVDD and the supply are used.

Input Coupling Capacitors

The AC-coupling capacitors (C_{IN}) and input resistors (R_{IN}) form highpass filters that remove any DC bias from an input signal. See the <u>MAX98307 Typical Application</u> <u>Circuit</u> and <u>MAX98308 Typical Application Circuit</u>. C_{IN} prevents any DC components from the input signal source appearing at the amplifier outputs. The -3dB point of the highpass filter, assuming zero source impedance due to the input signal source, is given by:

$$f_{-3dB} = \frac{1}{2\pi \times R_{IN} \times C_{IN}}$$

Choose C_{IN} so that f_{-3dB} is well below the lowest frequency of interest. Setting f_{-3dB} too high affects the amplifier's low-frequency response. Use capacitors with adequately low voltage coefficient (X5R or X7R recommended) for best low frequency THD+N performance.

Charge-Pump Capacitor Selection

Use capacitors with an equivalent series resistance (ESR) less than $50m\Omega$ for optimum performance. Low-ESR ceramic capacitors minimize the output resistance of the charge pump. For best performance over the extended temperature range, select capacitors with an X7R dielectric and a rated voltage of at least 6.3V.

Charge-Pump Flying Capacitor

The value of the charge-pump flying capacitor affects the load regulation and output resistance of the charge pump. A charge-pump flying capacitor value that is too small (less than 1 μ F) degrades the amplifier's ability to provide sufficient current drive. Increasing the value of this flying capacitor and decreasing the ESR improves load regulation and reduces the charge-pump output impedance, which improves the output power and efficiency of the amplifier. A 4.7 μ F or greater value, low-ESR capacitor is recommended.

Charge-Pump Hold Capacitor

The charge-pump hold capacitor value and ESR directly affect the ripple at the charge-pump rail, PVSS. Increasing the charge-pump hold capacitor value reduces output ripple. Likewise, decreasing the ESR of this capacitor reduces both ripple and output resistance. A 10μ F or greater value, low-ESR capacitor is recommended.

Layout and Grounding

Proper layout and grounding are essential for optimum performance. Good grounding improves audio performance and prevents switching noise from coupling into the audio signal.

Use wide, low-resistance output traces. As load impedance decreases, the current drawn from the device increases. At higher current, the resistance of the output traces decrease the power delivered to the load. For example, if 2W is delivered from the device output to an 8Ω load through $100m\Omega$ of total speaker trace, 1.97W is delivered to the speaker. If power is delivered through $10m\Omega$ of total speaker trace, 1.998W is delivered to the speaker. Wide output, supply, and ground traces also improve the power dissipation of the device.

The ICs are inherently designed for excellent RF immunity. For best performance, add ground fills around all signal traces on top or bottom PCB planes.

3.3W Mono Class DG Multilevel Audio Amplifier

Thermal Considerations

Class DG multilevel amplifiers provide much better efficiency and thermal performance than a comparable Class AB or Class G amplifiers. However, the system's thermal performance must be considered with realistic expectations and include consideration of many parameters. This section examines Class DG multilevel amplifiers using general examples to illustrate good design practices.

MAX98307 (TQFN) Applications Information

The exposed pad is the primary route of keeping heat away from the IC. With a bottom-side exposed pad, the PCB and its copper becomes the primary heatsink for the Class DG multilevel amplifier. Solder the exposed pad to a large copper polygon. Add as much copper as possible from this polygon to any adjacent pin on the amplifier as well as to any adjacent components, provided these connections are at the same potential. These copper paths must be as wide as possible. Each of these paths contributes to the overall thermal capabilities of the system.

The copper polygon to which the exposed pad is attached should have multiple vias to the opposite side of the PCB. Make this polygon as large as possible within the system's constraints for signal routing.

MAX98308 (WLP) Applications Information

For the latest application details on WLP construction, dimensions, tape carrier information, PCB techniques, bump-pad layout, and recommended reflow temperature profile, as well as the latest information on reliability testing results, refer to Application Note 1891: *Wafer-Level Packaging (WLP) and Its Applications*.

PART	GAIN SET	PIN-PACKAGE
MAX98307ETE+	External	16 TQFN-EP*
MAX98307ETE/V+	External	16 TQFN-EP*
MAX98308EWC+	Internal	12 WLP

Ordering Information

Note: All devices operate over the -40°C to +85°C temperature range.

+Denotes a lead(Pb)-free/RoHS-compliant package.

N denotes an automotive qualified part.

*EP = Exposed pad.

3.3W Mono Class DG Multilevel Audio Amplifier

Package Information

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
16 TQFN-EP	T1633+5	<u>21-0136</u>	<u>90-0032</u>
12 WLP	W121A1+1	<u>21-0542</u>	Refer to Application Note 1891

3.3W Mono Class DG Multilevel Audio Amplifier

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/11	Initial release	_
1	8/11	Updated output power conditions in the Electrical Characteristics table	4
2	9/11	Updated Electrical Characteristics table and TOC 20	2, 4, 8
3	9/11	Added EP to the <i>Pin Description</i> section and removed future product reference for the MAX98308	12, 17
4	3/12	Added RIN typical values for all gains and corrected error on TOCs 1–6	3, 6
5	3/15	Added MAX98307ETE/V+ to Ordering Information	17
6	6/16	Updated package code and outline number in Package Information table	18



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